

JAN2N3636L

Request a Quote

JAN2N3636L Information

Heisener.com	Part Number	JAN2N3636L
	Manufacturer	Microsemi Corporation
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
	Description	TRANS PNP 175V 1A
	Package	TO-205AA, TO-5-3 Metal Can
		For the pricing/inventory/lead time, please contact
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



JAN2N3636L Specifications

Manufacturer Part Number	JAN2N3636L
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-205AA, TO-5-3 Metal Can
Series	Military, MIL-PRF-19500/357
Transistor Type	PNP
Current - Collector (Ic) (Max)	1A
Voltage - Collector Emitter Breakdown (Max)	175V
Vce Saturation (Max) @ Ib, Ic	600mV @ 5mA, 50mA
Current - Collector Cutoff (Max)	10µA
DC Current Gain (hFE) (Min) @ Ic, Vce	50 @ 50mA, 10V
Power - Max	1W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-205AA, TO-5-3 Metal Can
Supplier Device Package	TO-5
	Report errors?

JAN2N3636L Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

JAN2N3636L Payment Methods





If you have any question about JAN2N3636L, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com